

END SEMESTER EXAMINATIONS (JANUARY 2022) - QUESTION PAPER - PART A

COURSE CODE : ICE 2151
COURSE NAME : Analog Electronic Circuits
SEMESTER : III
DATE OF EXAM : 27/01/2022
DURATION : 45 + 3 minutes

Instructions for Students:

- (1) ANSWER ALL THE QUESTIONS.
- (2) EACH QUESTION CARRIES 1 MARK.
- (3) YOU ARE INSTRUCTED TO INFORM THE INVIGILATOR AFTER SUBMISSION OF THIS FORM IN THE CHAT SECTION.

* Required

* This form will record your name, please fill your name.

1

STUDENT NAME: *

2

REGISTRATION NUMBER: *

3

If gate voltage of MOSFET is less than V_{TH} (1 Point)

- ☐ $I_D > 0$
- ☐ Channel is formed to conduct the current between source and drain
- ☐ Channel is depleted of free charge carriers
- ☐ All of the above

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MOSFET operates as variable resistor in the absence of (1 Point)

- ☐ Gate voltage
- ☐ Drain Voltage
- ☐ Channel Pinch-off phenomenon
- ☐ Channel length modulation

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The decrease in channel length after pinch off (1 Point)

- ☐ Reduces I_D to zero
- ☐ Has no effect on I_D
- ☐ Causes I_D to increase with V_{DS}
- ☐ Causes I_D to decrease with V_{DS}

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The gate oxide layer thickness of MOSFET (1 Point)

- ☐ None of the above
- ☐ Has no effect on MOSFET characteristics
- ☐ Is directly proportional to I_D
- ☐ Is inversely proportional to I_D

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The small signal model of the MOSFET is applicable in (1 Point)

- ☐ Cut-off region
- ☐ Triode region
- ☐ Deep triode region
- ☐ Saturation region

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In NMOS, (1 Point)

- ☐ Source and Drain are made up of n-type semiconductor
- ☐ All of the above
- ☐ Channel is made up of holes
- ☐ Substrate is made up of n-type semiconductor

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The MOSFETS M1 operates in ----- & ----- regions for the circuits shown in FIG.A & FIG.B. (1 Point)

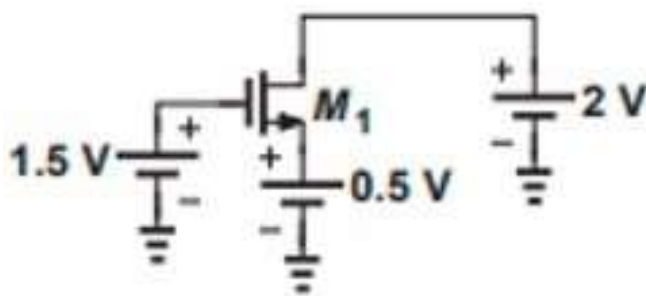


FIG. A

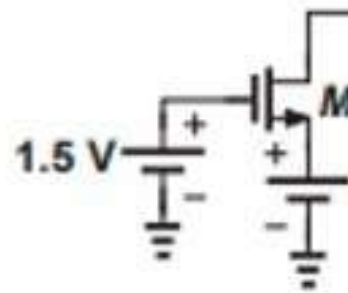


FIG. B

- ☐ Linear , Saturation
- ☐ Linear , Linear
- ☐ Saturation, Saturation
- ☐ Saturation , Linear

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An NMOS device with $\lambda = 0.1 \text{ V}^{-1}$ must provide a g_{m,r_o} of 20 with $V_{DS} = 1.5 \text{ V}$. The aspect ratio of the device to get a drain of 0.5 mA is -----.

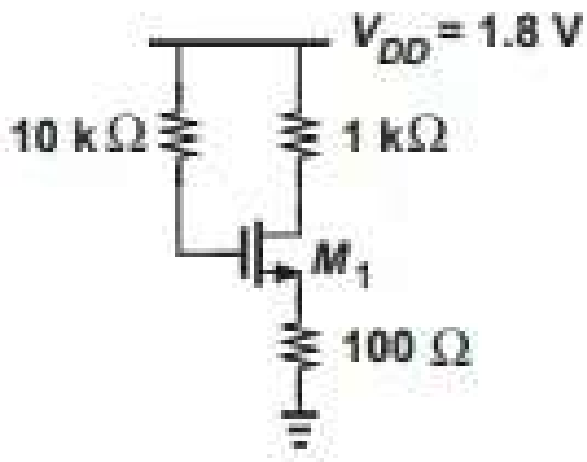
(1 Point)

- ☐ 1
- ☐ 120
- ☐ 5
- ☐ 8

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For the circuit shown, the maximum transconductance that M1 can provide (without going into the triode region) is -----.

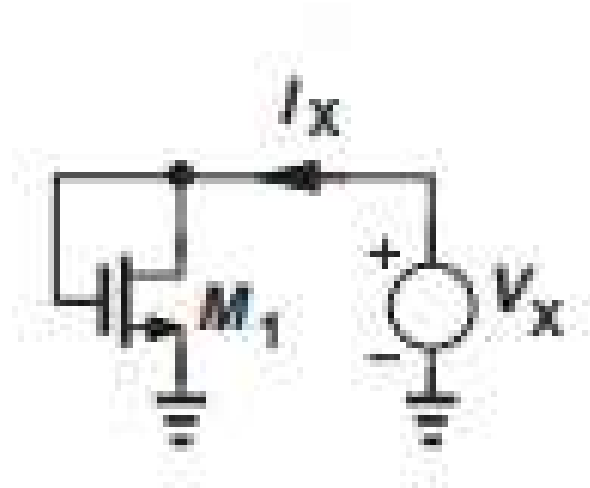
(1 Point)



- ☐ 50.234ms
- ☐ 12.121mS
- ☐ 1.276mS
- ☐ 0.588mS

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For the circuit shown, I_X variation w.r.t V_X is -----, for $V_X > V_{TH}$. (1 Point)



- ☐ Parabolic
- ☐ None of these.
- ☐ Exponential
- ☐ Linear

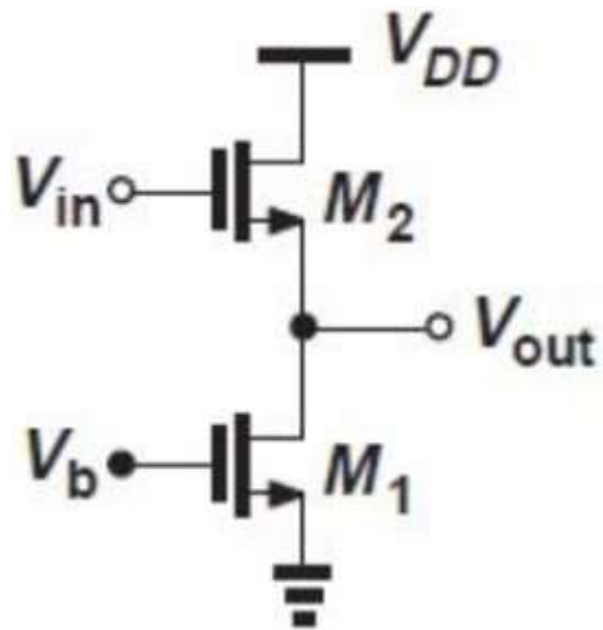
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CD amplifier can be used as buffer since it provides (1 Point)

- ☐ High Output impedance
- ☐ High current gain
- ☐ High voltage gain
- ☐ Low Input impedance

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The short-circuit transconductance of the circuit is (1 Point)



- ☐ $g_{m1} r_{o1}$
- ☐ g_{m1}
- ☐ $g_{m1} g_{m2}$
- ☐ g_{m2}

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Negative feedback leads to (1 Point)

- ☐ Increase in I/O resistance
- ☐ Increase in gain
- ☐ All of the above
- ☐ Increase in bandwidth

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Miller effect is seen in (1 Point)

- ☐ CS amplifier
- ☐ None of the above
- ☐ CD amplifier
- ☐ CG amplifier

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The differential pair rejects (1 Point)

- ☐ supply voltage
- ☐ Ripples in supply voltage
- ☐ Ripples in input signals
- ☐ input signal

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The currents flowing through the MOSFET's are

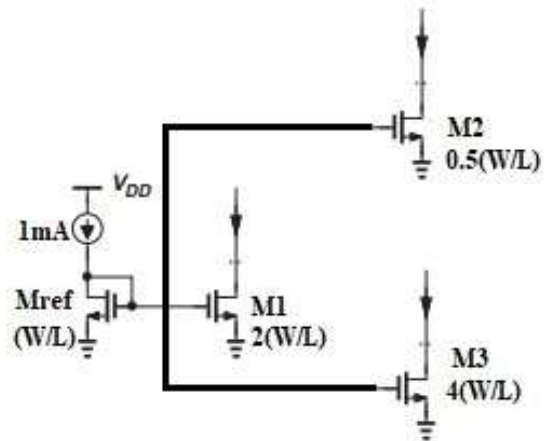
- i. 'M1' is 0.5mA , 'M2' is 2mA
- ii. 'M2' is 1mA , 'M3' is 0.25mA
- iii. 'M3' is 2mA , 'M1' is 1mA.

Of the three statements (i) is --- (ii) is ---- and (iii) is -----

.

(Assume $\lambda=0$ for all the MOSFET's, T = True, F = False)

(1 Point)



☐ T F F

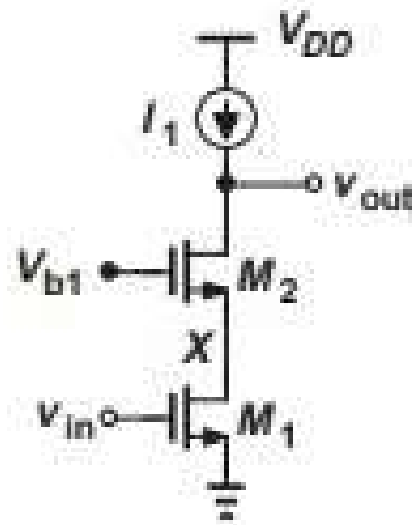
☐ F F F

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The circuit shown is designed to get a voltage gain of 10. To rise the voltage gain by twofold, following adjustments in the parameters are made

- i. I_D value is doubled without changing the aspect ratios of 'M1' & 'M2'.
 - ii. g_{m1} & r_{o1} values are doubled, r_{o2} is reduced by 0.5 keeping g_{m2} constant.
 - iii. g_{m2} & r_{o2} values are doubled, r_{o1} is reduced by 0.5 keeping g_{m1} constant.
- Of the three statements (i) is --- (ii) is ---- and (iii) is -----.
T = True, F = False.

(1 Point)


☐ T T F

☐ T T T

20

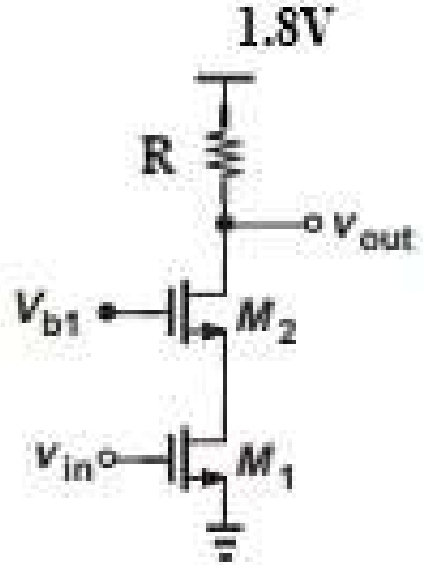
For the circuit shown below, following statements are made assuming 'M1' and 'M2' as identical MOSFET'S with over drive voltage $0.2V$, $r_o = 1.5K\Omega$ & drain current $1mA$.

i. If the value of 'R' is $1.5K\Omega$, voltage gain $A_v = 56.25$.

ii. If the value of 'R' is $1.8K\Omega$, Output resistance $R_{OUT} = 1.406K\Omega$.

Of the two statements (i) is --- and (ii) is ----.

T = True & F = False. (1 Point)



☐ T F

☐ F F

☐ T T

☐ F T

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In current mirrors, if gate-source voltage of two identical MOS transistors are equal, then the channel currents should be _____ (1 Point)

☐ Equal

☐ Different

☐ Both a and b

☐ None of the above

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Identify an oscillator from the below list which doesn't belong to low frequency oscillation? (1 Point)

- ☐ RC phase shift oscillator
- ☐ Twin T oscillators
- ☐ Wien bridge oscillator
- ☐ Crystal oscillator

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Hartley oscillator consists of_____ capacitors in its Tank circuit. (1 Point)

- ☐ Three
- ☐ Two
- ☐ Four
- ☐ One

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The input impedance_____ when current (Negative) feedback is applied to an amplifier. (1 Point)

- ☐ None of the above
- ☐ remain constant
- ☐ increases
- ☐ decreases

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Identify the wrong statement from the below list with reference to negative feedback amplifiers (1 Point)

- ☐ Improves gain stability
- ☐ Widens the separation between 3db frequency
- ☐ Increases gain – bandwidth product
- ☐ Reduces distortion

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Class AB power amplifier is commonly used in order_____ (1 Point)

- ☐ To overcome cross-over distortion
- ☐ To get maximum efficiency
- ☐ To remove even harmonics
- ☐ To reduce collector dissipation

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Compute the minimum power rating required for a transistor in Class A amplifier (With single transistor) if amplifier delivers 50W to a transformed coupled load? Assume transformer is ideal. (1 Point)

- ☐ 100W
- ☐ 50W
- ☐ 75W
- ☐ 25W

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Select the right answer for R_{in} and R_{out} ($\lambda > 0$) in Common Source topology of MOSFET (with R_s and R_D) (1 Point)

- ☐ ∞ and $R_D * [(1+g_{mro}) R_s + r_o]$
- ☐ ∞ and $[(1+g_{mro}) R_s + r_o]$
- ☐ ∞ and $R_D + [(1+g_{mro}) R_s + r_o]$
- ☐ ∞ and $R_D \parallel [(1+g_{mro}) R_s + r_o]$

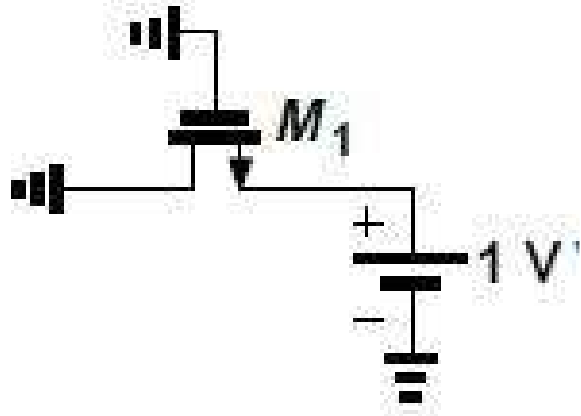
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A microphone with zero dc level drives a CS stage biased at $I_D = 0.5$ mA. If $W/L = 50$, $\mu_n C_{ox} = 100 \mu A/V^2$, $V_{TH} = 0.5$ V, and $V_{DD} = 1.8$ V, determine R_{Dmax} and A_{vmax} . Neglect channel length modulation. (1 Point)

- ☐ $R_D < 2.71$ & $A_v < 6.1$
- ☐ $R_D < 1.71$ & $A_v < 6.1$
- ☐ $R_D < 0.71$ & $A_v < 3.1$
- ☐ $R_D < 3.71$ & $A_v < 5.1$

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Find the region of operation of M1? (1 Point)



- ☐ On
- ☐ Saturation
- ☐ Off
- ☐ Triode

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The frequency of oscillation in LC Oscillator is _____ Inductor and Capacitor (1 Point)

- ☐ Independent of the values of
- ☐ Proportional to square of
- ☐ Inversely proportional to square root of
- ☐ Directly proportional to

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The commonly observed application of Hartley Oscillator is in____ (1 Point)

- ☐ Radio receivers
- ☐ None of the above
- ☐ TV receivers
- ☐ Radio transmitters

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